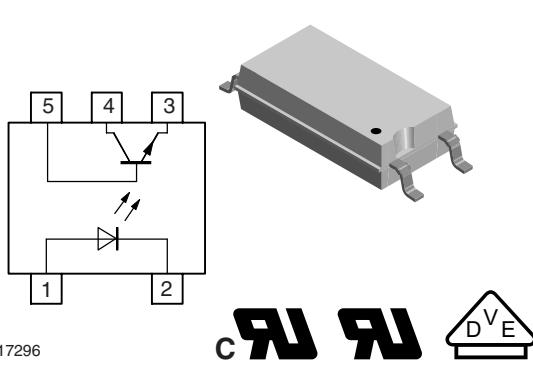


Optocoupler, Phototransistor Output, SOP-6L5, Half Pitch, Long Mini-Flat Package


RoHS
COMPLIANT

DESCRIPTION

The TCLT11.. series consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 5-lead SOP-6L package.

The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

APPLICATIONS

- Switchmode power supplies
- Computer peripheral interface
- Microprocessor system interface

AGENCY APPROVALS

- UL1577, file no. E76222 system code W, double protection
- CSA E76222 22.2 bulletin 5A
- BSI IEC 60950 IEC 60065
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending
- FIMKO

Note

See the safety standard approval list "Agency Table" for more detailed information.

ORDER INFORMATION

PART	REMARKS
TCLT1100	CTR 50 to 600 %, SOP-6L5
TCLT1102	CTR 63 to 125 %, SOP-6L5
TCLT1103	CTR 100 to 200 %, SOP-6L5
TCLT1104	CTR 160 to 320 %, SOP-6L5
TCLT1105	CTR 50 to 150 %, SOP-6L5
TCLT1106	CTR 100 to 300 %, SOP-6L5
TCLT1107	CTR 80 to 160 %, SOP-6L5
TCLT1108	CTR 130 to 260 %, SOP-6L5
TCLT1109	CTR 200 to 400 %, SOP-6L5

Note

Available only on tape and reel.

TCLT11..Series

Vishay Semiconductors

Optocoupler, Phototransistor Output,
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Package



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_P \leq 10 \mu s$	I_{FSM}	1.5	A
Power dissipation		P_{diss}	100	mW
Junction temperature		T_j	125	°C
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
Collector peak current	$t_P/T = 0.5, t_P \leq 10 \text{ ms}$	I_{CM}	100	mA
Power dissipation		P_{diss}	150	mW
Junction temperature		T_j	125	°C
COUPLER				
Isolation test voltage (RMS)		V_{ISO}	5000	V _{RMS}
Total power dissipation		P_{tot}	250	mW
Operating ambient temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature ⁽²⁾		T_{sld}	260	°C

Notes

(1) $T_{amb} = 25$ °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(2) Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = \pm 50 \text{ mA}$	V_F		1.25	1.6	V
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$	C_j		50		pF
OUTPUT						
Collector emitter voltage	$I_C = 1 \text{ mA}$	V_{CEO}	70			V
Emitter collector voltage	$I_E = 100 \mu \text{A}$	V_{ECO}	7			V
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}, E = 0$	I_{CEO}		10	100	nA
COUPLER						
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V_{CEsat}			0.3	V
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega$	f_c		110		kHz
Coupling capacitance	$f = 1 \text{ MHz}$	C_k		0.3		pF

Note

$T_{amb} = 25$ °C, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

**CURRENT TRANSFER RATIO**

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	V _{CE} = 5 V, I _F = 5 mA	TCLT1100	CTR	50		600	%
	V _{CE} = 5 V, I _F = 10 mA	TCLT1102	CTR	63		125	%
		TCLT1103	CTR	100		200	%
		TCLT1104	CTR	160		320	%
	V _{CE} = 5 V, I _F = 1 mA	TCLT1102	CTR	22	45		%
		TCLT1103	CTR	34	70		%
		TCLT1104	CTR	56	100		%
	V _{CE} = 5 V, I _F = 5 mA	TCLT1105	CTR	50		150	%
		TCLT1106	CTR	100		300	%
		TCLT1107	CTR	80		160	%
		TCLT1108	CTR	130		260	%
		TCLT1109	CTR	200		400	%

MAXIMUM SAFETY RATINGS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward current		I _F			130	mA
OUTPUT						
Power dissipation		P _{diss}			265	mW
COUPLER						
Rated impulse voltage		V _{IOTM}			8	kV
Safety temperature		T _{si}			150	°C

Note

According to DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending (see figure 1). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V _{pd}	2.0			kV
Partial discharge test voltage - lot test (sample test)	t _{Tr} = 60 s, t _{test} = 10 s, (see figure 2)	V _{IOTM}	8			kV
		V _{pd}	1.68			kV
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹			Ω
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω

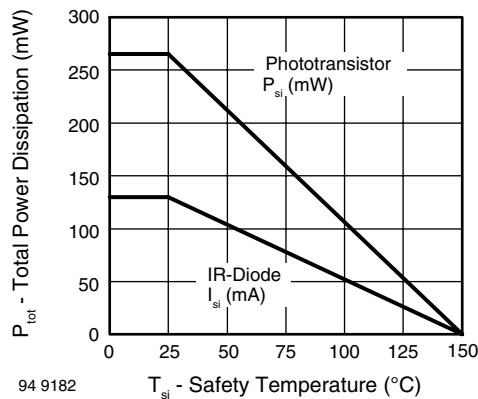


Fig. 1 - Derating Diagram

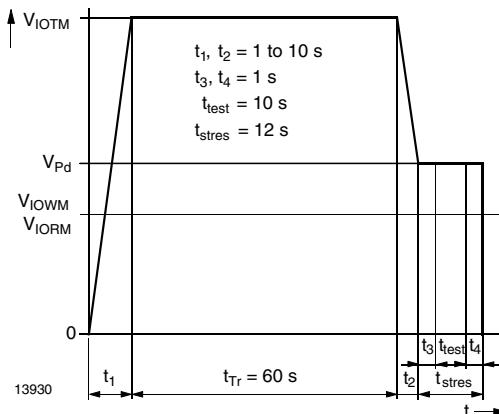
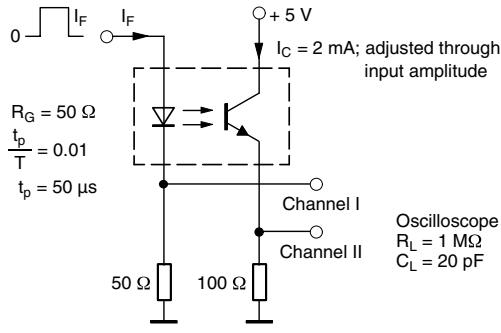


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2(VDE 0884)/DIN EN 60747-, IEC 60747

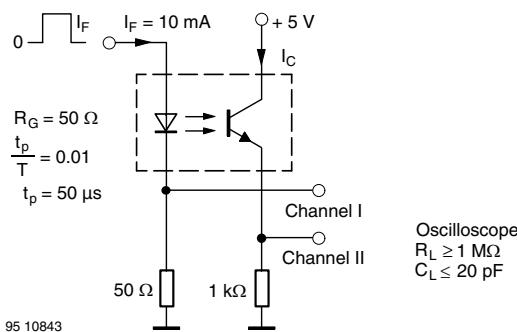
SWITCHING CHARACTERISTICS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$, (see figure 3)	t_d		3.0		μs
Rise time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$, (see figure 3)	t_r		3.0		μs
Turn-on time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$, (see figure 3)	t_{on}		6.0		μs
Storage time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$, (see figure 3)	t_s		0.3		μs
Fall time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$, (see figure 3)	t_f		4.7		μs
Turn-off time	$V_S = 5 \text{ V}$, $I_C = 2 \text{ mA}$, $R_L = 100 \Omega$, (see figure 3)	t_{off}		5.0		μs
Turn-on time	$V_S = 5 \text{ V}$, $I_F = 10 \text{ mA}$, $R_L = 1 \text{k}\Omega$, (see figure 4)	t_{on}		9.0		μs
Turn-off time	$V_S = 5 \text{ V}$, $I_F = 10 \text{ mA}$, $R_L = 1 \text{k}\Omega$, (see figure 4)	t_{off}		10.0		μs



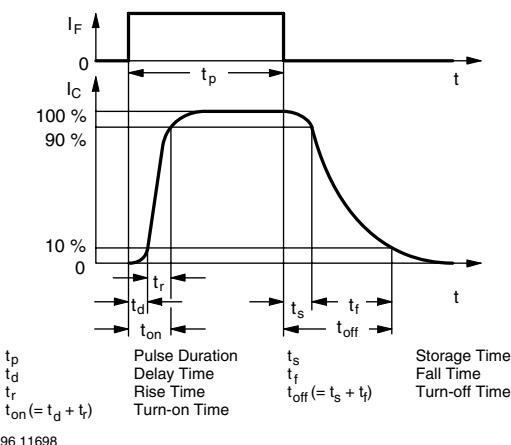
95 10804

Fig. 3 - Test Circuit, Non-Saturated Operation



95 10843

Fig. 4 - Test Circuit, Saturated Operation



96 11698

Fig. 5 - Switching Times

TYPICAL CHARACTERISTICS

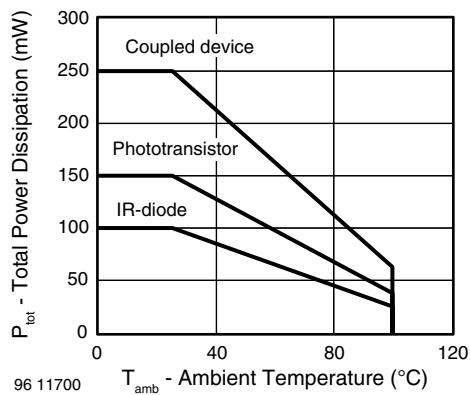
 $T_{amb} = 25^\circ\text{C}$, unless otherwise specified


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

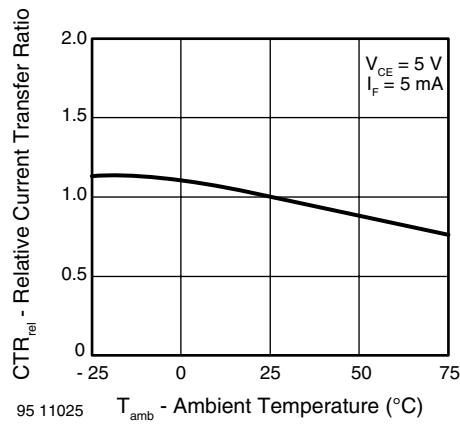
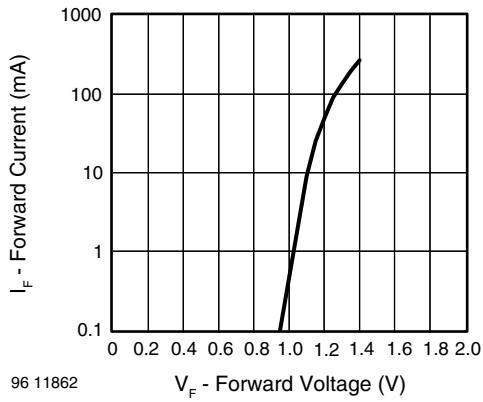

 Fig. 8 - Relative Current Transfer Ratio vs.
 Ambient Temperature


Fig. 7 - Forward Current vs. Forward Voltage

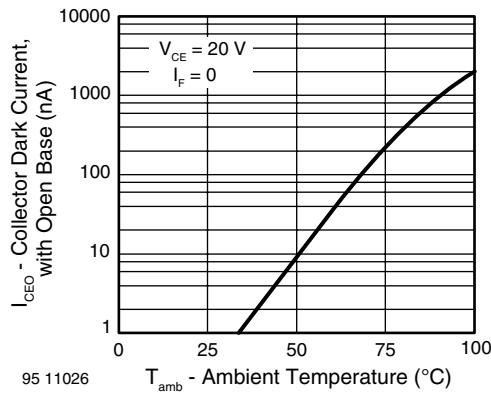


Fig. 9 - Collector Dark Current vs. Ambient Temperature

TCLT11..Series

Vishay Semiconductors

Optocoupler, Phototransistor Output,
SOP-6L5, Half Pitch, Long Mini-Flat
Package

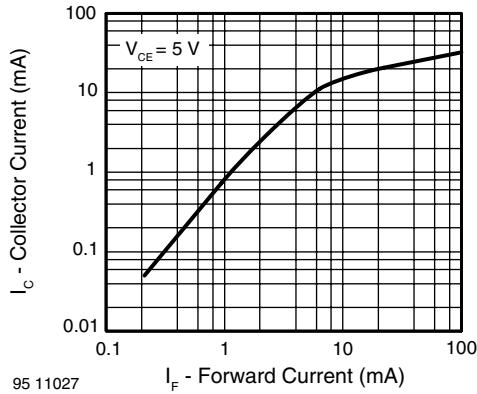


Fig. 10 - Collector Current vs. Forward Current

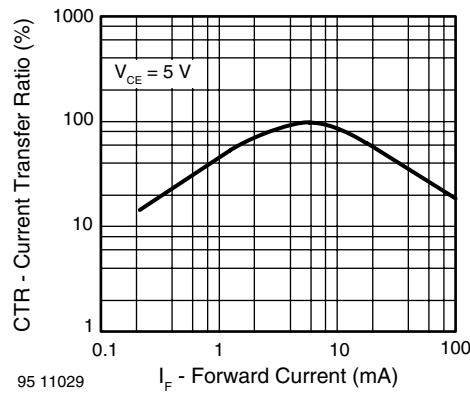


Fig. 13 - Current Transfer Ratio vs. Forward Current

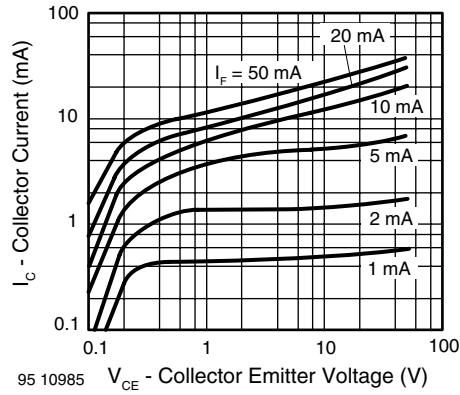


Fig. 11 - Collector Current vs. Collector Emitter Voltage

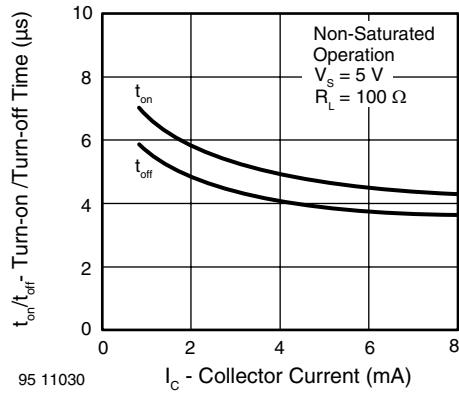


Fig. 14 - Turn-on/off Time vs. Collector Current

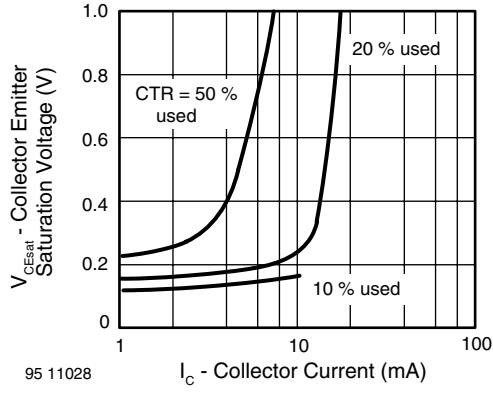


Fig. 12 - Collector Emitter Saturation Voltage vs.
Collector Current

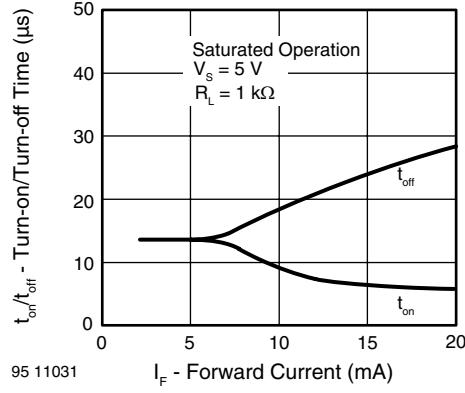
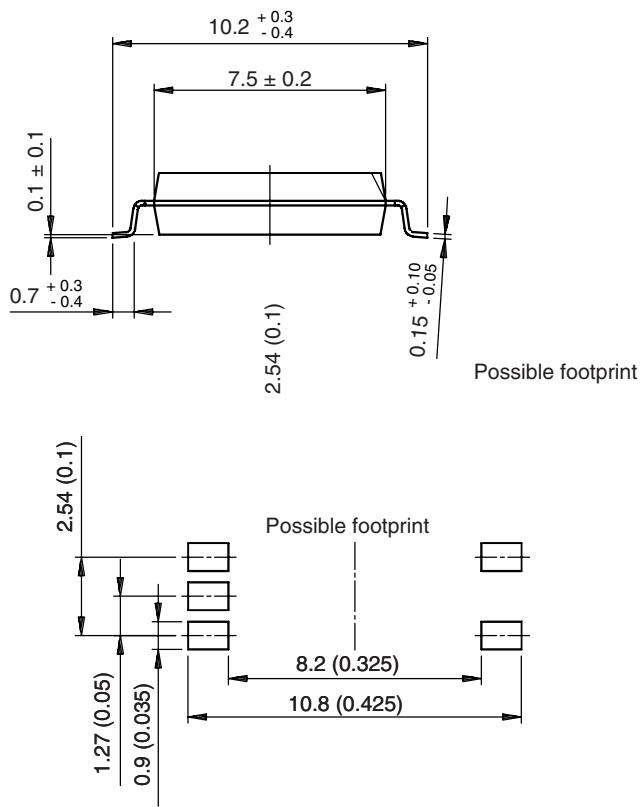
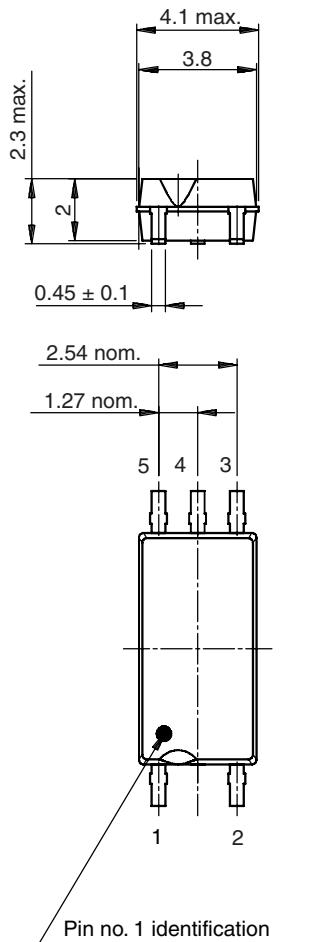


Fig. 15 - Turn-on/off Time vs. Forward Current

Optocoupler, Phototransistor Output,
SOP-6L5, Half Pitch, Long Mini-Flat
Package

Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters (inches)



Drawing-No.: 6.544-5331.02-4

Issue: 2; 29.06.00



technical drawings
according to DIN
specifications

15227

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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